

Data sheet acquired from Harris Semiconductor SCHS246

# CD74AC251, CD74ACT251

August 1998

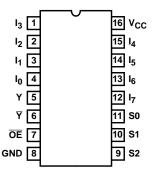
# 8-Input Multiplexer, Three-State

### **Features**

- Buffered Inputs
- Typical Propagation Delay
  - 6ns at  $V_{CC} = 5V$ ,  $T_A = 25^{\circ}C$ ,  $C_L = 50pF$
- Exceeds 2kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latchup-Resistant CMOS Process and Circuit Design
- Speed of Bipolar FAST™/AS/S with Significantly Reduced Power Consumption
- Balanced Propagation Delays
- AC Types Feature 1.5V to 5.5V Operation and Balanced Noise Immunity at 30% of the Supply
- ±24mA Output Drive Current
  - Fanout to 15 FAST™ ICs
  - Drives  $50\Omega$  Transmission Lines

### **Pinout**

CD74AC251, CD74ACT251 (PDIP, SOIC) TOP VIEW



# Description

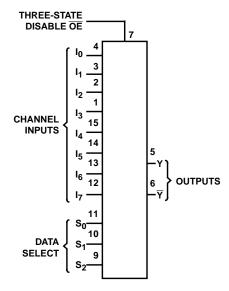
The CD74AC251 and CD74ACT251 8-input multiplexers that utilize the Harris Advanced CMOS Logic technology. This multiplexer features both true (Y) and complement ( $\overline{Y}$ ) outputs as well as an Output Enable ( $\overline{OE}$ ) input. The OE must be at a LOW logic level to enable this device. When the  $\overline{OE}$  input is HIGH, both outputs are in the high-impedance state. When enabled, address information on the data select inputs determines which data input is routed to the Y and  $\overline{Y}$  outputs.

# **Ordering Information**

PART NUMBER	TEMP. RANGE ( <sup>o</sup> C)	PACKAGE	PKG. NO.
CD74AC251E	0 to 70 <sup>o</sup> C, -40 to 85, -55 to 125	16 Ld PDIP	E16.3
CD74ACT251E	0 to 70°C, -40 to 85, -55 to 125	16 Ld PDIP	E16.3
CD74AC251M	0 to 70°C, -40 to 85, -55 to 125	16 Ld SOIC	M16.15
CD74ACT251M	0 to 70°C, -40 to 85, -55 to 125	16 Ld SOIC	M16.15

- 1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
- Wafer and die for this part number is available which meets all electrical specifications. Please contact your local sales office or Harris customer service for ordering information.

# Functional Diagram



**TRUTH TABLE** 

		INP	UTS	OUTI	PUTS
	SELECT	•			
S2	S1	S0	OUTPUT ENABLE OE	Y	Ÿ
Х	Х	Х	Н	Z	Z
L	L	L	L	I <sub>0</sub>	Īō
L	L	Н	L	I <sub>1</sub>	Ī <sub>1</sub>
L	Н	L	L	l <sub>2</sub>	Ī₂
L	Н	Н	L	I <sub>3</sub>	Ī3
Н	L	L	L	l <sub>4</sub>	Ī <sub>4</sub>
Н	L	Н	L	l <sub>5</sub>	Ī <sub>5</sub>
Н	Н	L	L	I <sub>6</sub>	Ī <sub>ē</sub>
Н	Н	Н	L	l <sub>7</sub>	Ī₹

H = High logic level, L = Low logic level, Z = High impedance (off), X = Irrelevant, I<sub>0</sub>, I<sub>1</sub>...I<sub>7</sub> = The level of the respective input

# **Absolute Maximum Ratings**

# DC Supply Voltage, V $_{CC}$ ... -0.5V to 6V DC Input Diode Current, I $_{IK}$ For V $_{I}$ < -0.5V or V $_{I}$ > V $_{CC}$ + 0.5V ... ... $\pm 20$ mA DC Output Diode Current, I $_{OK}$ For V $_{O}$ < -0.5V or V $_{O}$ > V $_{CC}$ + 0.5V ... ... $\pm 50$ mA DC Output Source or Sink Current per Output Pin, I $_{O}$ For V $_{O}$ > -0.5V or V $_{O}$ < V $_{CC}$ + 0.5V ... ... $\pm 50$ mA DC V $_{CC}$ or Ground Current, I $_{CC}$ or I $_{GND}$ (Note 3) ... ... $\pm 100$ mA

### **Thermal Information**

Thermal Resistance (Typical, Note 5)	θ <sub>JA</sub> (ºC/W)
PDIP Package	
SOIC Package	
Maximum Junction Temperature (Plastic Package)	150 <sup>0</sup> C
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300 <sup>0</sup> C

### **Operating Conditions**

Temperature Range, T <sub>A</sub>
Supply Voltage Range, V <sub>CC</sub> (Note 4)
AC Types1.5V to 5.5V
ACT Types
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub>
Input Rise and Fall Slew Rate, dt/dv
AC Types, 1.5V to 3V 50ns (Max)
AC Types, 3.6V to 5.5V
ACT Types, 4.5V to 5.5V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### NOTES:

- 3. For up to 4 outputs per device, add  $\pm 25 \text{mA}$  for each additional output.
- 4. Unless otherwise specified, all voltages are referenced to ground.
- 5.  $\theta_{JA}$  is measured with the component mounted on an evaluation PC board in free air.

### **DC Electrical Specifications**

		TEST CONDITIONS		v <sub>cc</sub>	25°C		-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
AC TYPES					-	-		-	-	-	
High Level Input Voltage	V <sub>IH</sub>	-	-	1.5	1.2	-	1.2	-	1.2	-	V
				3	2.1	-	2.1	-	2.1	-	V
				5.5	3.85	-	3.85	-	3.85	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	1.5	-	0.3	-	0.3	-	0.3	V
				3	-	0.9	-	0.9	-	0.9	V
				5.5	-	1.65	-	1.65	-	1.65	V
High Level Output Voltage	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.05	1.5	1.4	-	1.4	-	1.4	-	V
			-0.05	3	2.9	-	2.9	-	2.9	-	V
			-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-4	3	2.58	-	2.48	-	2.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V

# DC Electrical Specifications (Continued)

			ST ITIONS	v <sub>cc</sub>	25	°c		C TO °C		C TO 5°C	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
Low Level Output Voltage	$V_{OL}$	V <sub>IH</sub> or V <sub>IL</sub>	0.05	1.5	-	0.1	-	0.1	-	0.1	V
			0.05	3	-	0.1	-	0.1	-	0.1	V
			0.05	4.5	-	0.1	-	0.1	-	0.1	V
			12	3	-	0.36	-	0.44	-	0.5	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	Н	V <sub>CC</sub> or GND	-	5.5	-	±0.1	-	±1	-	±1	μА
Three-State Leakage Current	I <sub>OZ</sub>	V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = V <sub>CC</sub> or GND	-	5.5	-	±0.5	-	±5	-	±10	μА
Quiescent Supply Current MSI	I <sub>CC</sub>	V <sub>CC</sub> or GND	0	5.5	-	8	-	80	-	160	μА
ACT TYPES											
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V
Low Level Output Voltage	$V_{OL}$	V <sub>IH</sub> or V <sub>IL</sub>	0.05	4.5	-	0.1	-	0.1	-	0.1	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	-	V <sub>CC</sub> or GND	-	5.5	-	±0.1	-	±1	-	±1	μА
Three-State or Leakage Current	I <sub>OZ</sub>	V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = V <sub>CC</sub> or GND	-	5.5	-	±0.5	-	±5	-	±10	μΑ
Quiescent Supply Current MSI	Icc	V <sub>CC</sub> or GND	0	5.5	-	8	-	80	-	160	μА
Additional Supply Current per Input Pin TTL Inputs High 1 Unit Load	Δl <sub>CC</sub>	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	2.4	-	2.8	-	3	mA

- 6. Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.
- 7. Test verifies a minimum  $50\Omega$  transmission-line-drive capability at  $85^{\circ}$ C,  $75\Omega$  at  $125^{\circ}$ C.

# **ACT Input Load Table**

INPUT	UNIT LOAD
S0, S1, S3	1
OE	1
I <sub>0</sub> - I <sub>7</sub>	1

NOTE: Unit load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications Table, e.g., 2.4mA max at 25°C.

# **Switching Specifications** Input $t_r$ , $t_f$ = 3ns, $C_L$ = 50pF (Worst Case)

			-40 <sup>4</sup>	C TO 85°	С	-55			
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
AC TYPES								!	!
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	1.5	-	-	153	-	-	169	ns
Data to Y Output		3.3 (Note 9)	4.9	-	17.2	4.7	-	18.9	ns
		5 (Note 10)	3.5	-	12.3	3.4	-	13.5	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	1.5	-	-	169	-	-	186	ns
Data to		3.3	5.4	-	19	5.2	-	20.9	ns
		5	3.8	-	13.5	3.7	-	14.9	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	1.5	=	-	207	-	-	228	ns
Select to Y Output		3.3	6.6	-	23.2	6.4	-	25.5	ns
		5	4.7	-	16.5	4.6	-	18.2	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	1.5	-	-	223	-	-	245	ns
Select to $\overline{Y}$ Output		3.3	7.1	-	24.9	6.9	-	27.4	ns
		5	5.1	-	17.8	4.9	-	19.6	ns
Propagation Delay,	t <sub>PZH</sub> , t <sub>PZL</sub> , t <sub>PHZ</sub> , t <sub>PLZ</sub>	1.5	-	-	155	-	-	169	ns
Output Enable and Output Disable to Output		3.3	5.2	-	18.7	5.1	-	20.3	ns
		5	3.5	-	12.3	3.4	-	13.5	ns
Three-State Output Capacitance	CO	-	-	-	15	-	-	15	pF
Input Capacitance	C <sub>I</sub>	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C <sub>PD</sub> (Note 11)	-	-	120	-	-	120	-	pF
ACT TYPES									
Propagation Delay, Data to Y Output	t <sub>PLH</sub> , t <sub>PHL</sub>	5 (Note 10)	3.5	-	12.3	3.4	-	13.5	ns
Propagation Delay, Data to ₹ Output	t <sub>PLH</sub> , t <sub>PHL</sub>	5	3.8	-	13.5	3.7	-	14.9	ns
Propagation Delay, Select to Y Output	t <sub>PLH</sub> , t <sub>PHL</sub>	5	4.7	-	16.5	4.6	-	18.2	ns
Propagation Delay, Select to ₹ Output	t <sub>PLH</sub> , t <sub>PHL</sub>	5	5.1	-	17.8	4.9	-	19.6	ns
Propagation Delay, Output Enable and Output Disable to Output	t <sub>PZH</sub> , t <sub>PZL</sub> , t <sub>PHZ</sub> , t <sub>PLZ</sub>	5	3.5	-	12.3	3.4	-	13.5	ns

# Switching Specifications Input $t_r$ , $t_f$ = 3ns, $C_L$ = 50pF (Worst Case) (Continued)

			-40°	C TO 85°	С	-55	°C TO 12	5°C	
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Three-State Output Capacitance	CO								
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C <sub>PD</sub> (Note 11)	-	-	45	-	-	45	-	pF

- 8. Limits tested 100%.
- 9. 3.3V Min is at 3.6V. Max is at 3V.
- 10. 5V Min is at 5.5V, Max is at 4.5V.
- 11.  $C_{PD}$  is used to determine the dynamic power consumption per device.  $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$  where  $f_i$  input frequency,  $C_L$  is output load capacitance,  $V_{CC}$  is supply voltage.

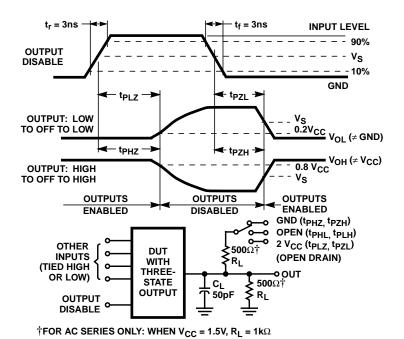


FIGURE 1. THREE-STATE PROPAGATION DELAY WAVEFORMS AND TEST CIRCUIT

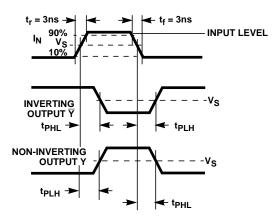
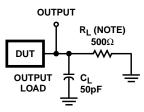


FIGURE 2. PROPAGATION DELAY TIMES



NOTE: For AC Series Only: When  $V_{CC}$  = 1.5V,  $R_L$  = 1k $\Omega$ .

	CD74AC	CD74ACT
Input Level	V <sub>CC</sub>	3V
Input Switching Voltage, V <sub>S</sub>	0.5 V <sub>CC</sub>	1.5V
Output Switching Voltage, V <sub>S</sub>	0.5 V <sub>CC</sub>	0.5 V <sub>CC</sub>

FIGURE 3. PROPAGATION DELAY TIMES

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### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74AC251M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC251M	Samples
CD74AC251M96E4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC251M	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# **PACKAGE OPTION ADDENDUM**

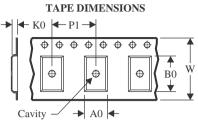
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# **PACKAGE MATERIALS INFORMATION**

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# TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

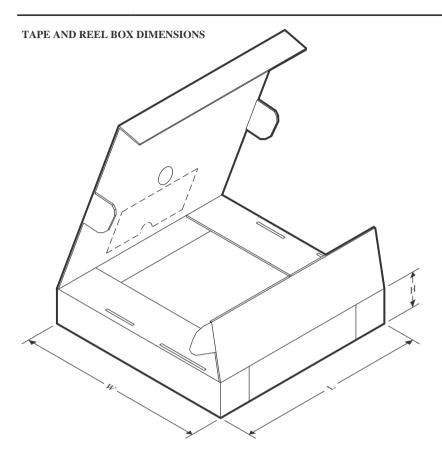
### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74AC251M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

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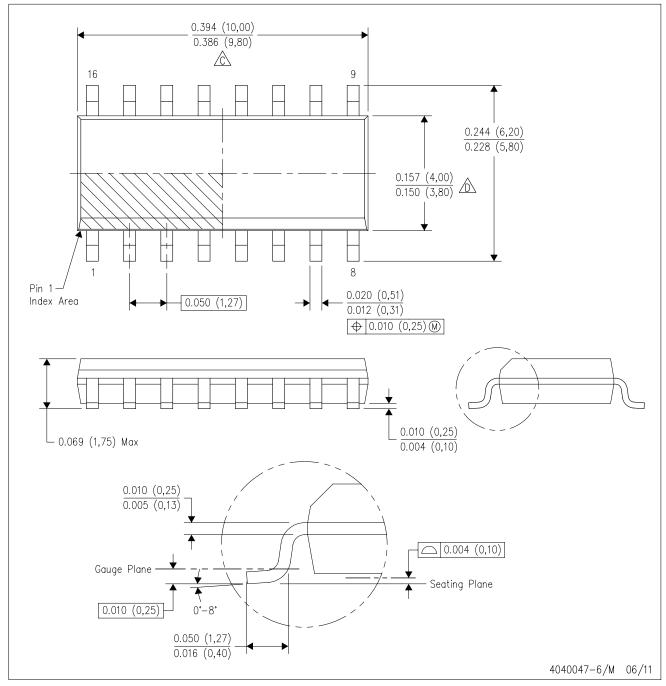


### \*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
ı	CD74AC251M96	SOIC	D	16	2500	340.5	336.1	32.0	

# D (R-PDS0-G16)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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